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## VS-MURB1620CTHM3, VS-MURB1620CT-1HM3

Vishay Semiconductors

## Ultrafast Rectifier, 2 x 8 A FRED Pt®



Base

common

cathode

Q 2

SHAY

TO-262AA Base common cathode

# Anode Common Anode

VS-MURB1620CTHM3

le Common Anode 1 cathode 2

1 cathode 2 VS-MURB1620CT-1HM3

Common

Anode

Anode

PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	2 x 8 A							
V <sub>R</sub>	200 V							
V <sub>F</sub> at I <sub>F</sub>	0.895 V							
t <sub>rr</sub> (typ)	19 ns							
T <sub>J</sub> max.	175 °C							
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA							
Circuit configuration	Common cathode							

### FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Peak repetitive reverse voltage		V <sub>RRM</sub>		200	V				
Average rectified forward current	per leg			8.0					
	total device	I <sub>F(AV)</sub>	Rated V <sub>R</sub> , T <sub>C</sub> = 150 °C	16	٨				
Non-repetitive peak surge current per leg		I <sub>FSM</sub>		100	A				
Peak repetitive forward current per leg		I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 150 °C	16					
Operating junction and storage temperatures		T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA		-	-				
	V <sub>F</sub>	I <sub>F</sub> = 8 A	-	-	0.975	V			
Forward voltage		I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	-	0.895				
Deverse lectrone current	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	-	5				
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	250	μΑ			
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	25	-	pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

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1

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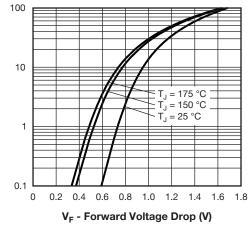
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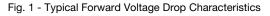
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, dI_F/dt = 10$	-	19	-					
Reverse recovery time		T <sub>J</sub> = 25 °C		-	20	-	ns			
		T <sub>J</sub> = 125 °C		-	34	-				
Deals recovery our rest	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 200 A/µs V <sub>B</sub> = 160 V	-	1.7	-	A nC			
Peak recovery current		T <sub>J</sub> = 125 °C		-	4.2	-				
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	23	-				
		T <sub>J</sub> = 125 °C		-	75	-				

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C			
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	3.0				
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	50	°C/W			
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-				
Weight			-	2.0	-	g			
Weight			-	0.07	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking davias		Case style D <sup>2</sup> PAK (TO-263AB) MURB1620CTH							
Marking device		Case style TO-262AA	MURB1620CT-1H						







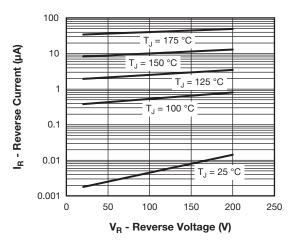


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

Revision: 15-Nov-2019

2

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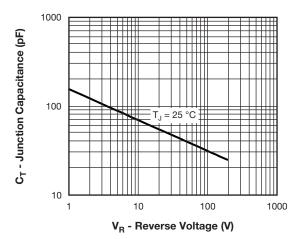


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

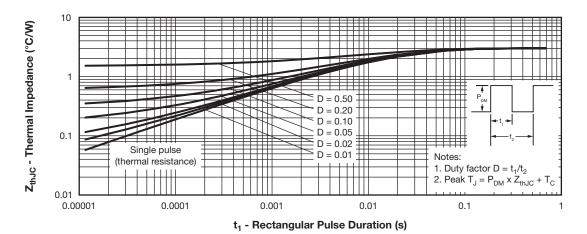
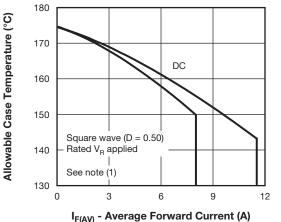
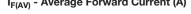
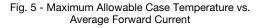


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics







### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$ 

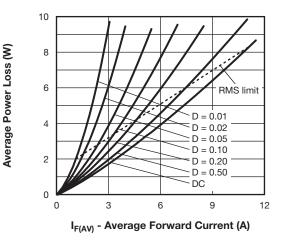


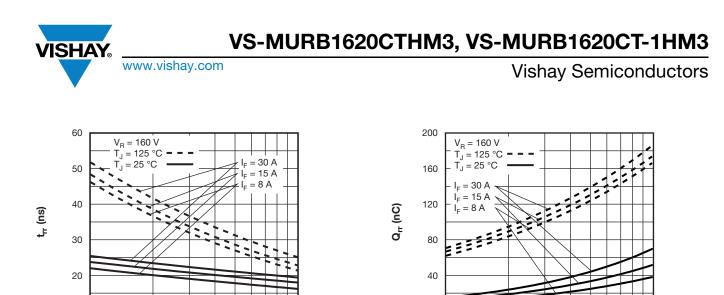
Fig. 6 - Forward Power Loss Characteristics

Revision: 15-Nov-2019

3

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1000

0

100

dl<sub>F</sub>/dt (A/µs)

Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

10

100



1000

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

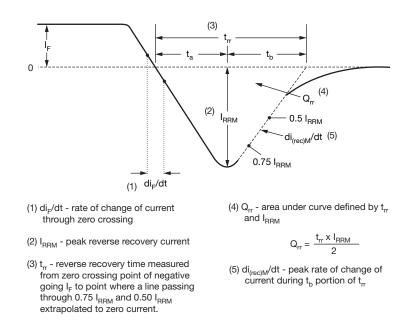


Fig. 9 - Reverse Recovery Waveform and Definitions

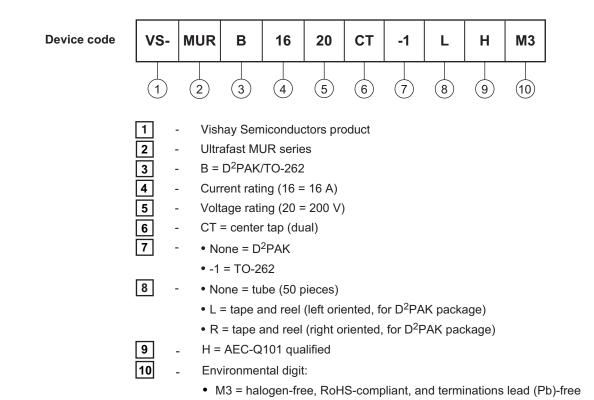
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### **ORDERING INFORMATION TABLE**

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ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MURB1620CTHM3	50	1000	Antistatic plastic tube						
VS-MURB1620CT-1HM3	50	1000	Antistatic plastic tube						
VS-MURB1620CTLHM3	800	800	13" diameter reel						
VS-MURB1620CTRHM3	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95046					
Dimensions	TO-262AA	www.vishay.com/doc?95419					
Part marking information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95444					
Fait marking information	TO-262AA	www.vishay.com/doc?95443					
Packaging information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95032					

## **Outline Dimensions**



D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

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SYMBOL	MILLIM	IETERS	INC	HES	NOTES		SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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1

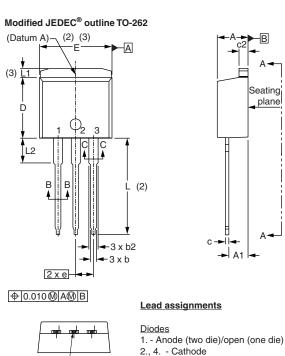
## **Outline Dimensions**



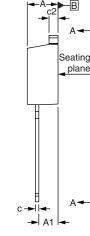
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**TO-262** 

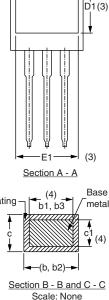
### **DIMENSIONS** in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 \_ 1.65 0.065 3 \_ 3.36 0.132 0.146 L2 3.71

3. - Anode

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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